

	Type	L #	Hits	Search Text	DBs
1	BRS	L1	156851	438/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
2	BRS	L2	48023	1 and (DRAM or transistor)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
3	BRS	L3	54	2 and (gate near segment?)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
4	BRS	L4	5	3 and raised near (STI or isolation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
5	BRS	L5	194	noble-wendell-p.in.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
6	BRS	L6	9	5 and (gate near segment?)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
7	BRS	L7	22	(gate near segment?).ti.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
8	BRS	L8	655356	DRAM or transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
9	BRS	L9	191	8 and (gate near segment?)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
10	BRS	L10	7	9 and raised near (STI or isolation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
11	IS&R	L11	5	(("5510286") or ("5753527") or ("5892707") or ("6194262") or ("6266268")).PN.	USPAT